

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Kar-Roy et al.**

Serial No.:

Filed:

**For: Method For Fabricating a High Density
Composite MIM Capacitor with Reduced
Voltage Dependence in Semiconductor Dies**

This is a Rule 1.53(b) divisional of parent
U.S. Application entitled "A High Density Composite
MIM Capacitor with Reduced Voltage Dependence in
Semiconductor Dies," Serial No. 10/410,937

Filed April 9, 2003 and assigned to the
assignee of the present application.

Examiner:

Group Art Unit:

PRELIMINARY AMENDMENT TO DIVISIONAL APPLICATION

Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir/Madam:

This amendment is directed to the accompanying 37 CFR §1.53(b) divisional application.

This divisional application is classified in Class 438, Subclass 396. The pending parent

application Serial No. 10/410,937 is classified in Class 257, Subclass 532 in Art Unit 2822.

Please enter the following amendments in the present Rule 1.53(b) divisional application.